

# BRCS3400MCQ

Rev. A Jun.-2022



DATA SHEET

SOT23-3          N    MOS

N - CHANNEL MOSFET in a SOT23-3 Plastic Package.

$V_{DS} (V) = 30V$

$I_D = 5.8 A (V_{GS} = 10V)$

$R_{DS(ON)} < 32m (V_{GS} = 10V)$

$R_{DS(ON)} < 36m (V_{GS} = 4.5V)$

$R_{DS(ON)} < 56m (V_{GS} = 2.5V)$

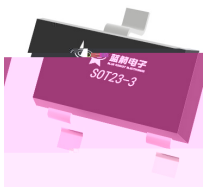
AEC-Q101

Qualified to AEC-Q101 Standards for High Reliability,

HF Product.

This device is suitable for use as a load switch or in PWM applications, Meet the stringent requirements of automotive applications.

## / Equivalent Circuit



PIN1    G

PIN 2    S

PIN 3    D

## / Marking

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	$V_{DS}$	30	V
Drain Current – Continuous	$I_D$	5.8	A
Drain Current- Continuous	$I_D(T_a=70^\circ\text{C})$	4.9	A
Pulsed Drain Current	$I_{DM}$	30	A
Gate-Source Voltage	$V_{GS}$	$\pm 12$	V
Total Power Dissipation	$P_D$	1.4	W
Total Power Dissipation	$P_D(T_a=70^\circ\text{C})$	1.0	W
Operating and Storage Junction Temperature Range	$T_J, T_{STG}$	-55 to 150	

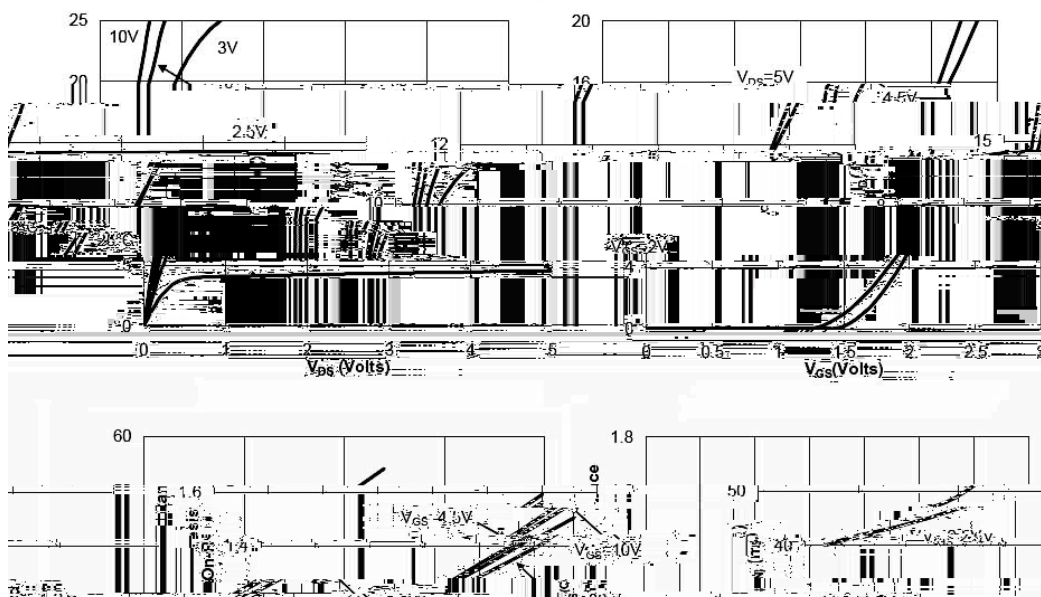
Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Drain–Source Breakdown Voltage	$BV_{DSS}$	$V_{GS}=0V$ $I_D=250\mu A$	30			V
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=24V$ $V_{GS}=0V$			1	$\mu A$
		$V_{DS}=24V$ $V_{GS}=0V$ $T_J=55$			5	$\mu A$
Gate–Body Leakage.	$I_{GSS}$	$V_{GS}=\pm 12V$ $V_{DS}=0V$			$\pm 0.1$	$\mu A$
On–State Drain Current	$I_{D(on)}$	$V_{GS}=4.5V$ $V_{DS}=5V$	30			A
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ $I_D=250\mu A$	0.65	1.1	1.45	V
Static Drain–Source On–Resistance	$R_{DS(on)(1)}$	$V_{GS}=10V$ $I_D=5.8A$		29	32	m
	$R_{DS(on)(2)}$	$V_{GS}=10V$ $I_D=5.8A$ $T_J=125$			39	
	$R_{DS(on)(3)}$	$V_{GS}=4.5V$ $I_D=5A$		32	36	
	$R_{DS(on)(4)}$	$V_{GS}=2.5V$ $I_D=4A$		40	56	
Forward Transconductance	$g_{FS}$	$V_{DS}=5V$ $I_D=5A$	10	15		S
Drain–Source Diode Forward Voltage	$V_{SD}$	$V_{GS}=0V$ $I_S=1A$		0.77	1	V
Input Capacitance	$C_{iss}$	$V_{DS}=15V$ $V_{GS}=0V$ $f=1MHz$		823	1030	pF
Output Capacitance	$C_{oss}$			99		

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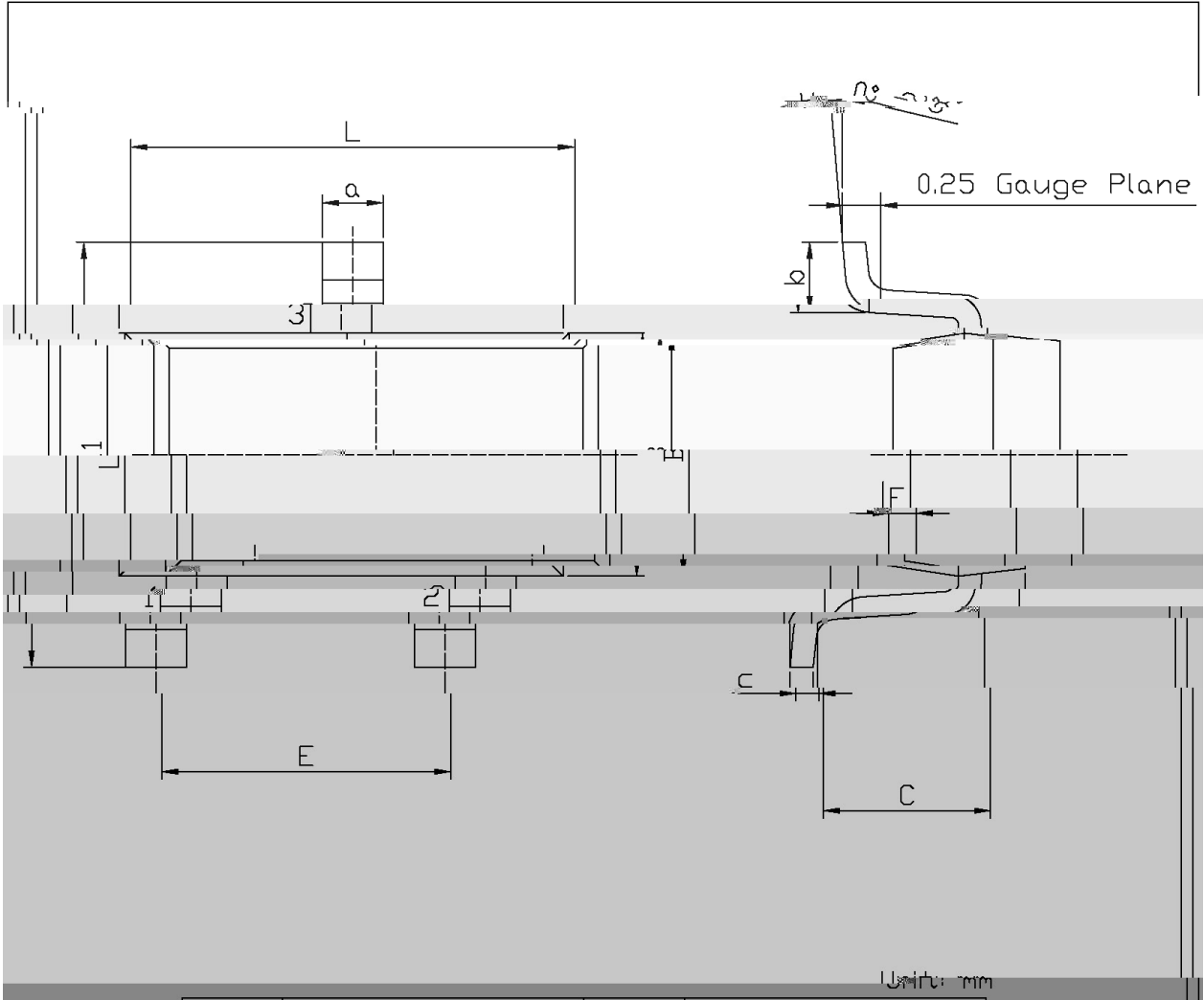
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Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Input Capacitance	$C_{iss}$	$V_{DS}=15V$ $V_{GS}=0V$ $f=1MHz$		823	1030	pF
Output Capacitance	$C_{oss}$			99		
Reverse Transfer Capacitance	$C_{rss}$			77		
Gate resistance	$R_g$	V				

/ Electrical Characteristic Curve

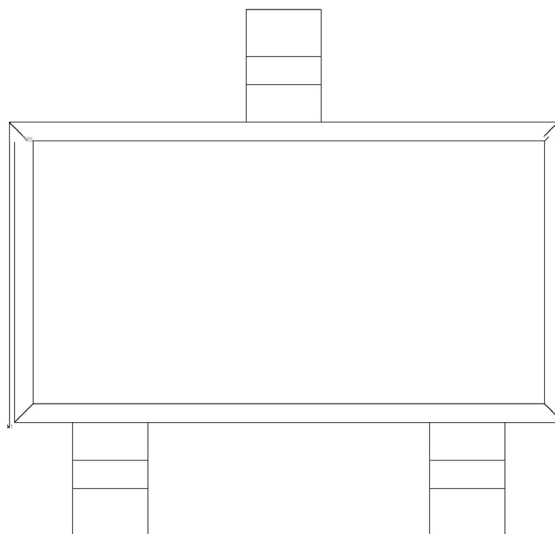


/ Package Dimensions



Dimension	Value
L	10.0
a	3.0
E	10.0
C	3.0
F	10.0

**/ Marking Instructions**



Q

AO

H

Note:

Q: Automobile halogen-free product Code

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